

DESCRIPTION

IR emitters.

# **VEMT3700F**

Vishay Semiconductors

## **Silicon NPN Phototransistor**



VEMT3700F is a high speed silicon NPN epitaxial planar phototransistor in a miniature PLCC-2 package. The

integrated daylight blocking filter is matched to 950 nm

#### FEATURES

- Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- High radiant sensitivity
- Fast response times
- Daylight blocking filter matched with 870 nm to 950 nm emitters
- Angle of half sensitivity:  $\phi = \pm 60^{\circ}$
- · Package notch indicates collector
- Package matched with IR emitter series VSML3710
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **APPLICATIONS**

- Photo interrupters
- Miniature switches
- Counters
- Encoders
- · Position sensors

PRODUCT SUMMARY				
COMPONENT	I <sub>ca</sub> (mA)	φ <b>(deg)</b>	λ <sub>0.5</sub> (nm)	
VEMT3700F	0.5	± 60	870 to 1050	

#### Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VEMT3700F-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2	
VEMT3700F-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	T CONDITION SYMBOL		UNIT	
Collector emitter voltage		V <sub>CEO</sub>	70	V	
Emitter collector voltage		V <sub>ECO</sub>	5	V	
Collector current		Ι <sub>C</sub>	50	mA	
Collector peak current	$t_p/T \le 0.1, t_p \le 10 \ \mu s$	I <sub>CM</sub>	100	mA	
Power dissipation		Pv	100	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	Acc. reflow solder profile fig. 10	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Soldered on PCB with pad dimensions: 4 mm x 4 mm	R <sub>thJA</sub>	400	K/W	

\*\* Please see document "Vishay Material Category Policy": <u>www.vishay.com/doc?99902</u>





**RoHS** COMPLIANT

GREEN (5-2008)\*\*

### Vishay Semiconductors

Silicon NPN Phototransistor





Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	$V_{CE} = 20 \text{ V}, \text{ E} = 0$	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	$V_{CE} = 5 V, f = 1 MHz, E = 0$	C <sub>CEO</sub>		3		pF
Collector ligth current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_{CE} = 5 \text{ V}$	I <sub>ca</sub>	0.25	0.5		mA
Angle of half sensitivity		φ		± 60		deg
Wavelength of peak sensitivity		λ <sub>p</sub>		940		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		870 to 1050		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 0.1 \text{ mA}$	V <sub>CEsat</sub>		0.15	0.3	V
Rise time, fall time	$V_S$ = 5 V, $I_C$ = 1 mA, $\lambda$ = 950 nm, $R_L$ = 1 $k\Omega$	t <sub>r</sub> /t <sub>f</sub>		6		μs
	$V_{S} = 5 \text{ V}, \text{ I}_{C} = 1 \text{ mA}, \lambda = 950 \text{ nm}, \\ R_{L} = 100 \ \Omega$	t <sub>r</sub> /t <sub>f</sub>		2		μs
Cut-off frequency	$V_{S}$ = 5 V, $I_{C}$ = 2 mA, $R_{L}$ = 100 $\Omega$	f <sub>c</sub>		180		kHz

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)



Fig. 2 - Collector Dark Current vs. Ambient Temperature



Fig. 3 - Relative Collector Current vs. Ambient Temperature



### Silicon NPN Phototransistor

### **Vishay Semiconductors**



Fig. 4 - Collector Light Current vs. Irradiance



Fig. 5 - Collector Light Current vs. Collector Emitter Voltage



Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage



Fig. 7 - Turn-on/Turn-off Time vs. Collector Current



Fig. 8 - Relative Spectral Sensitivity vs. Wavelength



Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

### **Vishay Semiconductors**

Silicon NPN Phototransistor



#### **PACKAGE DIMENSIONS** in millimeters





technical drawings according to DIN specifications

**Mounting Pad Layout** 



Drawing-No.: 6.541-5067.03-4 Issue: 1; 30.05.07 20873

### SOLDER PROFILE



Fig. 10 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 168 h Conditions:  $T_{amb} < 30$  °C, RH < 60 % Moisture sensitivity level 3, acc. to J-STD-020.

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

#### TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.



### Silicon NPN Phototransistor

### **Vishay Semiconductors**



Fig. 11 - Blister Tape



Fig. 12 - Tape Dimensions in mm for PLCC-2

#### **MISSING DEVICES**

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.



Fig. 13 - Beginning and End of Reel

The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.



Fig. 14 - Dimensions of Reel-GS08





#### **COVER TAPE REMOVAL FORCE**

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.